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FORM PTO-1449							Atty. Docket No.			Appln	Appln. No.	
							XA-10064			10/811,902		
LIST OF DOCUMENTS CITED BY APPLICANT												
·							Applicant Shoichiro CHIBA et al.					
							Filing			Group		
							HEREW				2827	
U.S. PATENT DOCUMENTS												
Examiner Initial		Document Number		Date		Name		Class	Sub- class	Filing Date		
	AA	5,581,503		12/03/96		Matsubara et al.		365	185.33			
1	AB	6,201,733 B1		03/13/01		Hiraki et al.		365	185.08	-		
	AC	5,561,627		10/01/96		Matsubara et al.		365	185.04			
	AD	4,659,828		04/21/87		Fong		544	399	 		
	ΑE	5,408,115		04/18/95		Chang		257	324	 		
(2)	AF	6,046,936		04/04/00		Tsujikawa et al.		365	185.03	-		
-	AG									<u> </u>		
	АН											
	ΑI											
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xaminer	1	Document Number		Date	 -		ountry		Class	Sub-	Translation	
nitial									-	class		
(2)	AJ	5-266219 10/15/93			Japan				_		No	
	AK	2000-149588	5/30/00		Japan		-		No			
	AL	7-334999	12/22/95		Japan					No		
	AM	5-136422	06/01/93		Japan					Abstract		
	AN	11-232886	08	08/27/99		Japan					No	
	AQ_											
	L	OTHER	(incl	uding author,	tit	le, da	te, pert	inent p	ages, etc.	.)		
0	AP Sohrab Kianian et al., "A Novel 3 Volts-Only, Small Sector Erase, High Density Flash E2PROM", IEEE, VLSI Technology Symposium, 1994 proceedings", pp. 71 - 72.											
	AQ											
	AR											
.xaminer Date Considered 4/05												
.XAMINER: Initial if reference considered, whether or not citation is in conformance ith MPEP 609; draw line through citation if not in conformance and not considered.												